

1N4148

Silicon Epitaxial Planar Diode for Various Detector,
Modulator, Demodulator

HITACHI

ADE-208-147C (Z)

Rev.3
Dec. 2001

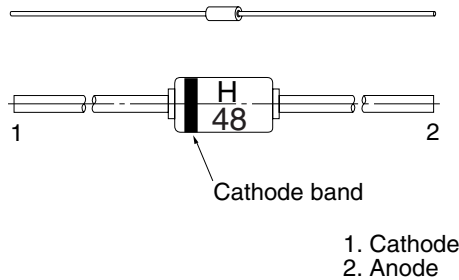
Features

- Low capacitance. ($C = 4.0 \text{ pF max}$)
- Short reverse recovery time. ($t_{rr} = 4.0 \text{ ns max}$)
- High reliability with glass seal.

Ordering Information

Type No.	Cathode band	Mark	Package Code
1N4148	Black	H48	DO-35

Outline



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	100	V
Reverse voltage	V_R	75	V
Peak forward current	I_{FM}	450	mA
Non-Repetitive peak forward surge current	I_{FSM}^*	1	A
Average forward current	I_O	150	mA
Power dissipation	P_d	500	mW
Junction temperature	T_j	200	°C
Storage temperature	T_{stg}	-65 to +200	°C

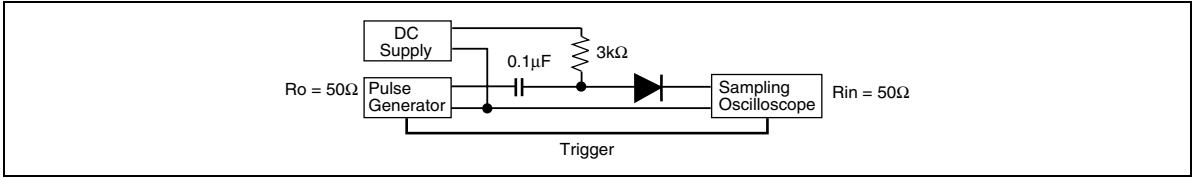
Note: Within 1s forward surge current.

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V_F	—	—	1.0	V	$I_F = 10\text{ mA}$
Reverse current	I_R	—	—	25	nA	$V_R = 20\text{ V}$
Capacitance	C	—	—	4.0	pF	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$
Reverse recovery time	t_{rr}^*	—	—	4.0	ns	$I_F = 10\text{ mA}$, $V_R = 6\text{ V}$, $I_{rr} = 1\text{ mA}$, $R_L = 100\text{ }\Omega$

Note: Reverse recovery time test circuit



Main Characteristic

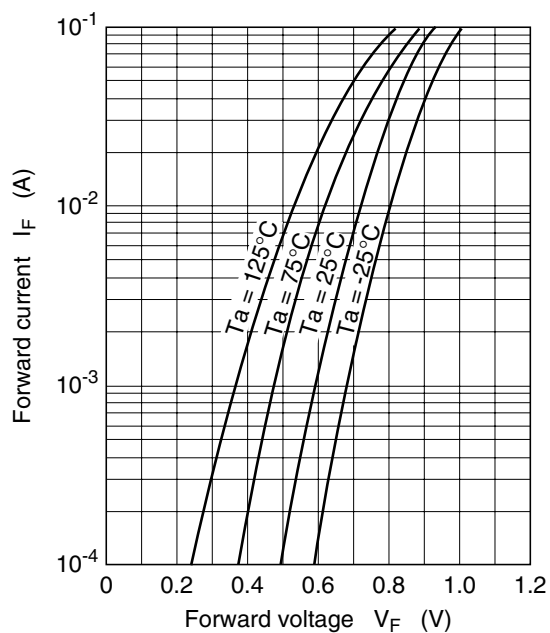


Fig.1 Forward current vs. Forward voltage

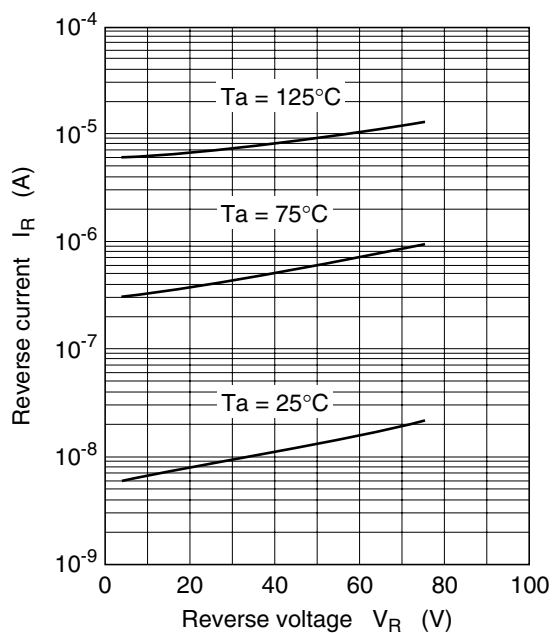


Fig.2 Reverse current vs. Reverse voltage

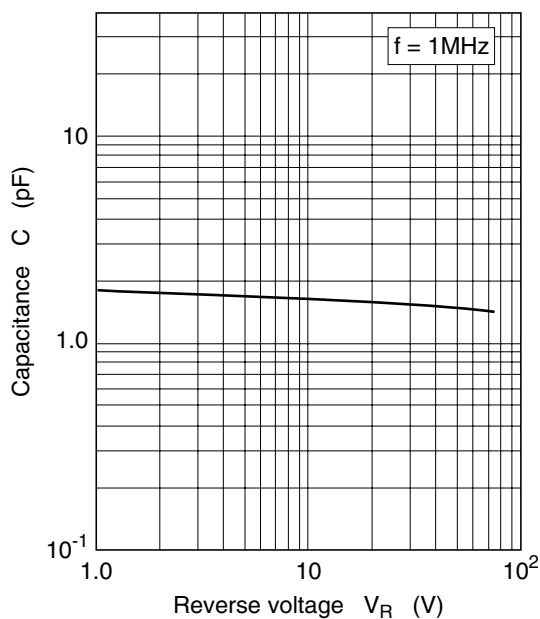
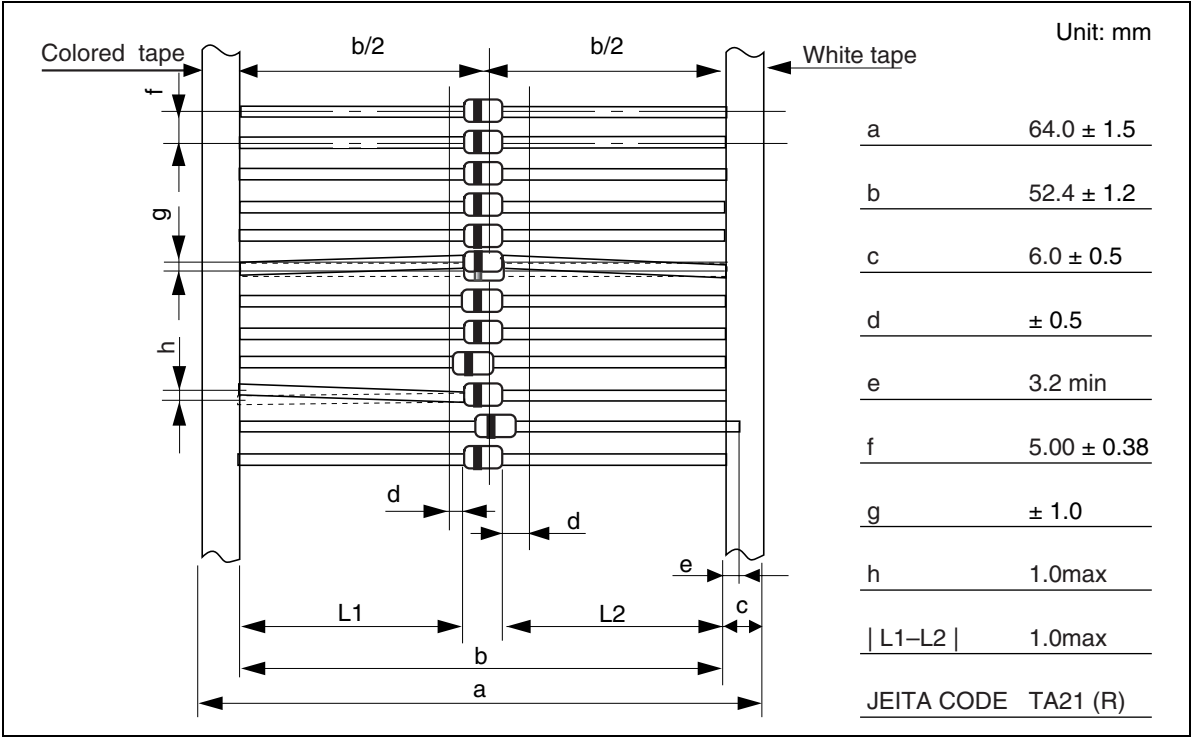
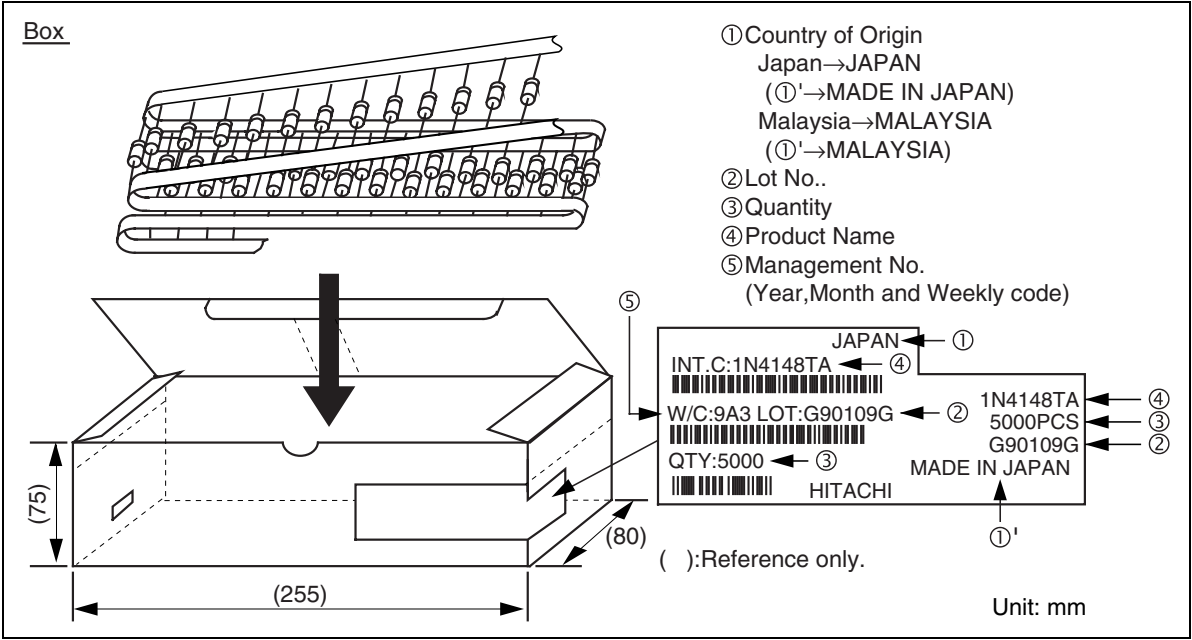


Fig.3 Capacitance vs. Reverse voltage

Ammo Pack Taping (TA TYPE)

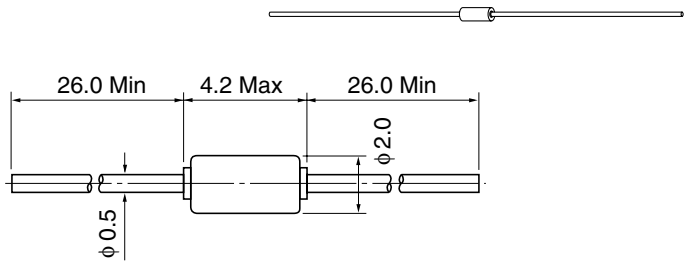


Taping appearance



Package Dimensions

As of July, 2001
Unit: mm



Hitachi Code	DO-35
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.13 g

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Sales Offices

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL <http://www.hitachisemiconductor.com/>

For further information write to:

Hitachi Semiconductor (America) Inc.
179 East Tasman Drive
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe Ltd.
Electronic Components Group
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585200

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straße 3
D-85622 Feldkirchen
Postfach 201, D-85619 Feldkirchen
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00
Singapore 049318
Tel: <65>-538-6533/538-8577
Fax: <65>-538-6933/538-3877
URL: <http://semiconductor.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road
Hung-Kuo Building
Taipei (105), Taiwan
Tel: <886>-(2)-2718-3666
Fax: <886>-(2)-2718-8180
Telex: 23222 HAS-TP
URL: <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon Hong Kong
Tel: <852>-(2)-735-9218
Fax: <852>-(2)-730-0281
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